



Low Pim

Contents

RAMSES Series

SPDT up to 18 GHz: R570xxxxxxLP Series	6-2 to 6-6
DPDT up to 18 GHz: R577xxxxxxxLP Series	.6-7 to 6-11
SPnT up to 18 GHz: R573xxxxxxLP Series	5-12 to 6-16

LOW PIM PART NUMBER SELECTION GUIDE*

Digita	l Position	R 1-3:	4: RF co	nnectors		5: Type		6: V	oltage	7: TTL	Option/F	Position		8: Op	tions		9: Terr	minals	LP 10-11:
Series	Configuration		N 12.4 GHz	SMA18GHz	Failsafe*	Latching*	Normally open*	12V	28V	Without TTL driver	With TTL driver	Number of positions	Without option	Positive common	Supression diodes	Positive common and suppression diodes	Solder pins	D-Sub connector	Low Pim
	SPDT	R570	1	4	1/2	3/4/5/6	-	2	3	0	1	-	0	1	3	4	0	5	LP
RAMSES	DPDT	R577	1	4	1/2	3/4/5/6	-	2	3	0	1	-	0	1	3	4	0	5	LP
	SPnT	R573	1	4	-	2/3	0/1	2	3	-	-	4/6	0	1	3	4	0	5	LP

Example of P/N: R573423600LP is a SP6T SMA 18 GHz, latching, 28 Vdc, without option, solder pins.



^{*}For specific part number creation and available options, see detailed part number selection for each series.



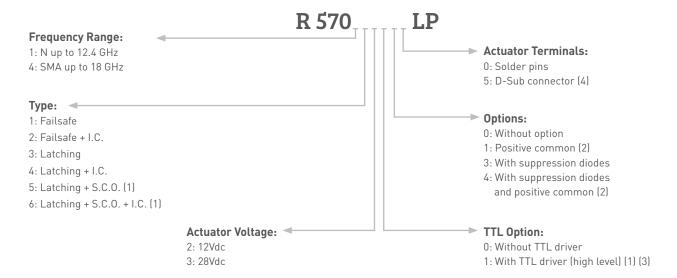
To meet growing market demands created by the deployment of 4G/LTE networks, Radiall has introduced a new range of Low PIM switches. RAMSES SPDT Low PIM switches are perfectly suited for RF test systems and test benches requiring excellent passive intermodulation performance up to 18 GHz, with a guarantee PIM performance of -160 dBc @ +43 dBm over a life span of 2 million switching cycles.

These products are specific to instrumentation and telecommunication applications.

Example of P/N:

R570413030LP is a SPDT SMA 18 GHz, failsafe, 28 Vdc, with supression diodes, solder pins.

PART NUMBER SELECTION



- I.C.: Indicator contact S.C.O.: Self Cut-Off
- (1): Suppression diodes are already included in Self Cut-OFF & TTL option
- [2]: Positive common shall be specified only with type 2, 3, 5 & 6 because failsafe models can be used with both polarities
- (3): Polarity is not relevant to application for switches with TTL driver
- (4): Available only for N models



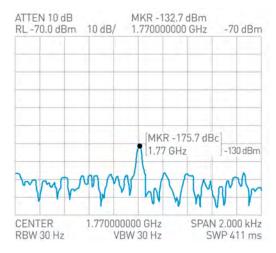
GENERAL SPECIFICATIONS

Operating mode		Fail	safe	Latcl	ning			
Nominal operating voltage (across operating temperature)	Vdc	12 (10.2 to 13)	28 (24 to 30)	12 (10.2 to 13)	28 (24 to 30)			
Coil resistance at 23°C (+/-10%)	Ω	47.5	275	58	350			
Operating current at 23°C	mA	250	102	210	80			
Average power			See Power Rating (Chart on page 1-13				
TTI input	High Level		2.2 to 5.5 Volts 8	300μA max 5.5 Volts				
TTL input	Low Level	0 to 0.8 Volts 20µA max 5.5 Volts						
Indicator rating		1 W / 30 V / 100 mA						
Switching time	ms		1	0				
Life (Min)		2 million cycles						
Connectors			SMA	4 - N				
Operating temperature range		-40°C to +85°C						
Storage temperature range		-55°C to +85°C						
Vibration (MIL STD 202, method 204D, co	ond.D)	10-2000 Hz, 20g operating						
Shock (MIL STD 202, method 213B, cond	Shock (MIL STD 202, method 213B, cond.C) 100g / 6 ms, ½ sine operating							

RF PERFORMANCES

Connectors	Freque	ncy range GHz	V.S.W.R. (max)	Insertion loss (max) dB	Isolation (min) dB	Impedance Ω	Third order intermodulation
		DC - 1	1.15	0.15	85		
		1 - 2	1.20	0.20	80		
N	DC - 12.4	2 - 3	1.25	0.25	75		
		3 - 8	1.35	0.35	70		-160 dBc @ +43 dBm
		8 - 12.4	1.50	0.50	60	50	(2 carriers 20W)
		DC - 3	1.10	0.15	80		
SMA	DC - 8	3 - 8	1.20	0.20	75		
SIMA	DC - 0	8 - 12.4	1.20	0.25	65		
		12.4 - 18	1.40	0.35	60		

OUTSTANDING PIM PERFORMANCE



Passive Intermodulation

Tone 1	1810 MHz, approximately 43 dBm
Tone 2	1850 MHz, approximately 43 dBm
3rd order PIM	160 dBc at 1770 MHz

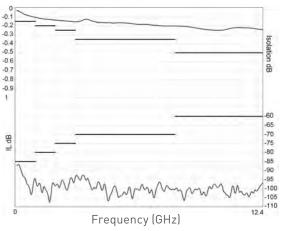
Depending on application, carrier powers and frequencies, PIM measurements can vary. PIM testing is not measured during product acceptance test.



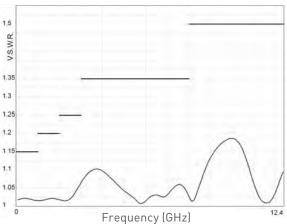
TYPICAL RF PERFORMANCES

Example: SPDT N up to 12.4 GHz

Insertion Loss and Isolation

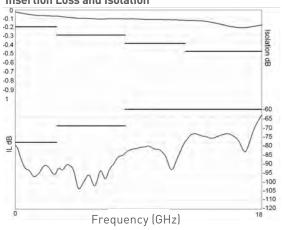


V.S.W.R.

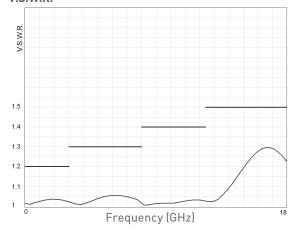


Example: SPDT SMA up to 18 GHz

Insertion Loss and Isolation



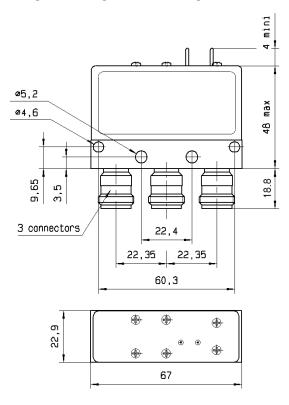
V.S.W.R.



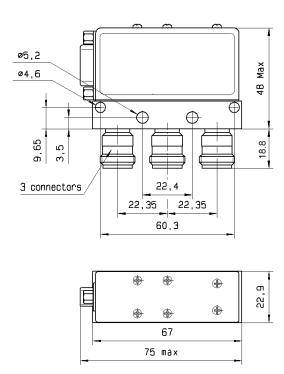


TYPICAL OUTLINE DRAWING

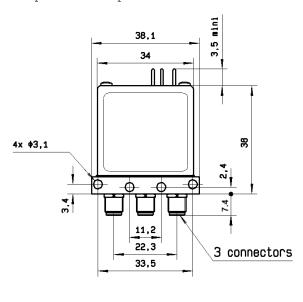
Example: SPDT N up to 12.4 GHz with pins

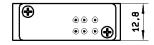


Example: SPDT N up to 12.4 GHz with D-sub



Example: SPDT SMA up to 18 GHz









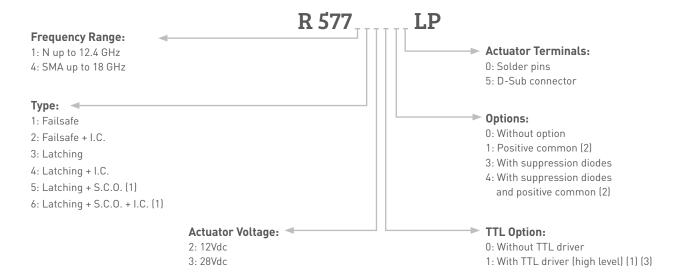
To meet growing market demands created by the deployment of 4G/LTE networks, Radiall has introduced a new range of Low PIM switches.RAMSES DPDT Low PIM switches are perfectly suited for RF test systems and test benches requiring excellent passive intermodulation performance up to 18 GHz, with a guarantee PIM performance of -160 dBc @ +43 dBm over a life span of 2 million switching cycles.

These products are specific to instrumentation and telecommunication applications.

Example of P/N:

R577163105 is a DPDT N 12.4 GHz latching with Indicators, Self Cut-Off, 28 Vdc, TTL driver, D-Sub connector.

PART NUMBER SELECTION



- I.C.: Indicator contact S.C.O.: Self Cut-Off
- (1): Suppression diodes are already included in Self Cut-OFF & TTL option
- (2): Positive common shall be specified only with type 2, 3, 5 & 6 because failsafe models can be used with both polarities
- (3): Polarity is not relevant to application for switches with TTL driver



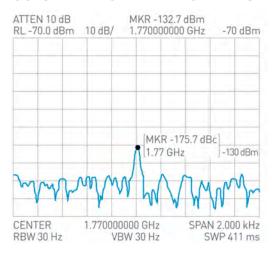
GENERAL SPECIFICATIONS

Operating mode		Norma	lly open	Latcl	hing		
Nominal operating voltage (across operating temperature)	Vdc	12 (10.2 to 13)	28 (24 to 30)	12 (10.2 to 13)	28 (24 to 30)		
Coil resistance at 23°C (+/-10%)	Ω	35	200	38	225		
Nominal operating current at 23°C	mA	340	140	320	125		
Average power			See Power Rating	Chart on page 1-13			
TTI innut	High Level		2.2 to 5.5 Volts	800µA max 5.5 Volts			
TTL input	Low Level	0 to 0.8 Volts 20µA max0.8 Volts					
Switching time (Max)	ms	15					
Life (Min)		2 million cycles					
Connectors		SMA - N					
Actuator terminals		Solder pins or male 9 pin D-Sub connector					
Operating temperature range			-40°C	to +85°C			
Storage temperature range			-55°C	to +85°C			
Vibration (MIL STD 202, method 204D, con	d.C)	10-2000 Hz, 10g operating					
Shock (MIL STD 202, method 213B, cond.0	;]		50g / 11 ms, ½ si	ne operating			

RF PERFORMANCES

Connectors	Frequer	ncy range GHz	V.S.W.R. (max)	Insertion loss (max) dB	Isolation (min) dB	Impedance Ω	Third order intermodulation
		DC - 1	1.15	0.15	85		
		1 - 2	1.20	0.20	80		
Ν	DC - 3 DC - 12.4	2 - 3	1.25	0.25	75		
		3 - 8	1.35	0.35	70		-160 dBc @ +43 dBm
		8 - 12.4	1.50	0.50	60	50	(2 carriers 20W)
		DC - 3	1.20	0.20	80		
SMA	DC - 3	3 - 8	1.30	0.30	70		
AIVIC	DC - 18	8 - 12.4	1.40	0.40	65		
		12.4 - 18	1.50	0.50	60		

OUTSTANDING PIM PERFORMANCE



Passive Intermodulation

Tone 1	1810 MHz, approximately 43 dBm
Tone 2	1850 MHz, approximately 43 dBm
3rd order PIM	160 dBc at 1770 MHz

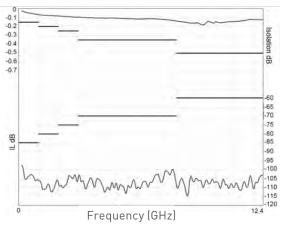
Depending on application, carrier powers and frequencies, PIM measurements can vary. PIM testing is not measured during product acceptance test.



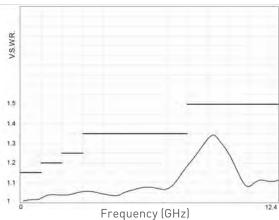
TYPICAL RF PERFORMANCES

Example: DPDT N up to 12.4 GHz

Insertion Loss and Isolation

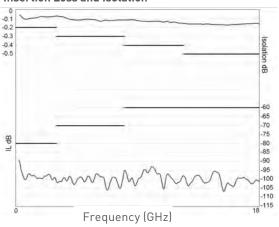


V.S.W.R.

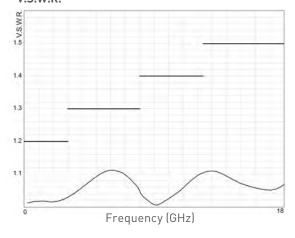


Example: DPDT N up to 18 GHz

Insertion Loss and Isolation



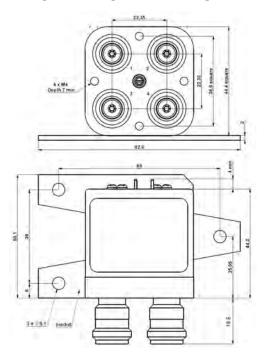
V.S.W.R.



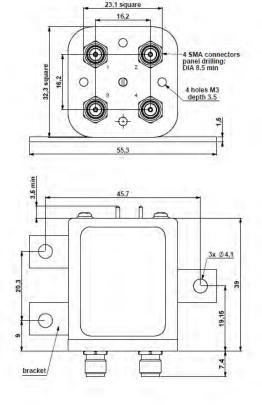


TYPICAL OUTLINE DRAWING

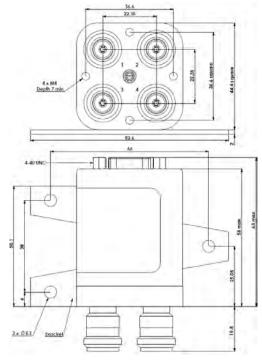
Example: DPDT N up to 12.4 GHz with pins



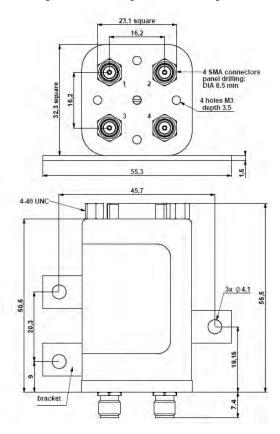
Example: DPDT SMA up to 18 GHz with pins



Example: DPDT N up to 12.4 GHz with D-sub



Example: DPDT SMA up to 18 GHz with pins







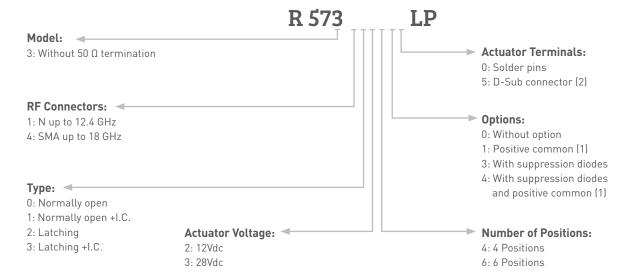
To meet growing market demands created by the deployment of 4G/LTE networks, Radiall has introduced a new range of Low PIM switches. RAMSES SPnT Low PIM switches are perfectly suited for RF test systems and test benches requiring excellent passive intermodulation performance up to 18 GHz, with a guarantee PIM performance of -160 dBc @ +43 dBm over a life span of 2 million switching cycles.

These products are specific to instrumentation and telecommunication applications.

Example of P/N:

R573403600LP is a SP6T SMA up to 18 GHz, Normally Open, 28 Vdc, without option and solder pins.

PART NUMBER SELECTION



- I.C.: Indicator contact
- (1) Standard products are equiped with negative common
- (2) Only for N models



GENERAL SPECIFICATIONS

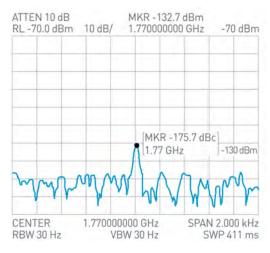
Operating mode		Norma	lly open	Latc	hing				
Nominal operating voltage (across operating temperature)	Vdc	12 (10.2 to 13)	28 (24 to 30)	12 (10.2 to 13)	28 (24 to 30)				
Coil resistance at 23°C (+/-10%)	Ω	47.5	275	38	225				
Nominal operating current at 23°C	mA	250	102	320 Reset SP4T: 1280 mA* Reset SP6T: 1920 mA*	125 Reset SP4T: 500 mA* Reset SP6T: 750 mA*				
Average power			See Power Rating	Chart on page 1-13					
TTL input	High Level		2.2 to 5.5 V (TTL Option) / 3.5 to 5.5 V (BCD Option)						
TTE IIIput	Low Level	0 to 0.8 V (TTL Option) / 0 to 1.5 V (BCD Option)							
Indicator rating		1 Watt / 30 V / 100 mA							
Switching time (Max)	ms		1	5					
Life (Min)		2 million cycles							
Connectors		SMA - N							
Actuator terminals		Solder pins or male 25 pin D-Sub connector							
Operating temperature range		-40°C to +85°C							
Storage temperature range		-55°C to +85°C							
Vibration (MIL STD 202, method 204D	, cond.D)	10-2000 Hz , 20g operating for SP3 to 6T							
Shock (MIL STD 202, method 213B, co	ond.C)		100g / 6 ms, ½ sine	operating for SP3 to 6T					

^{*}Reset: supply voltage time 1 sec. max./duty cycle 10%

RF PERFORMANCES

Connectors	Number of positions	Frequency range GHz		V.S.W.R. (max)	Insertion loss (max) dB	Isolation (min) dB	Impedance Ω	Third order intermodulation													
		DC - 18	DC - 3	1.20	0.20	80															
SMA			DC - 18	DC - 18	3 - 8	1.30	0.30	70													
SIVIA					DC - 16	DC - 16	DC = 10	DC = 16	DC = 10	DC = 16	DC - 10	DC = 16	DC = 16	DC = 16	DC = 16	8 - 12.4	1.40	0.40	60		-160 dBc @ +43 dBm
	4 and 6																	12.4 - 18	1.50	0.50	60
			DC - 3	1.20	0.20	80															
N		DC - 12.4	3 - 8	1.35	0.35	70															
				8 - 12.4	1.50	0.50	60														

OUTSTANDING PIM PERFORMANCE



Passive Intermodulation

Tone 1	1810 MHz, approximately 43 dBm
Tone 2	1850 MHz, approximately 43 dBm
3rd order PIM	160 dBc at 1770 MHz

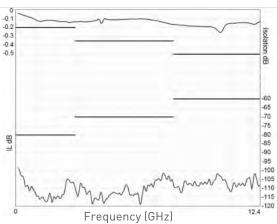
Depending on application, carrier powers and frequencies, PIM measurements can vary. PIM testing is not measured during product acceptance test.



TYPICAL RF PERFORMANCES

Example: SP6T N up to 12.4 GHz

Insertion Loss and Isolation

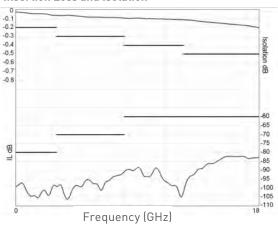




Frequency (GHz)

Example: SP6T SMA up to 18 GHz

Insertion Loss and Isolation

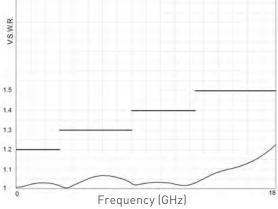




V.S.W.R.

1.5

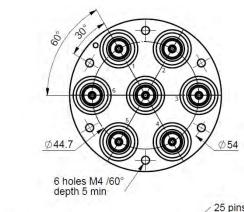
1.3

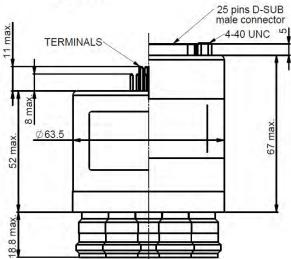




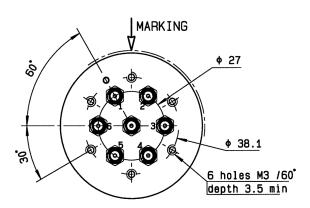
TYPICAL OUTLINE DRAWING

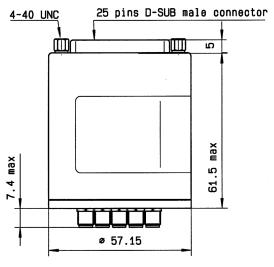
Example: SPnT N up to 12.4 GHz





Example: SPnT SMA up to 18 GHz

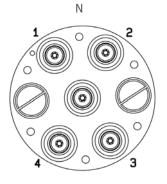


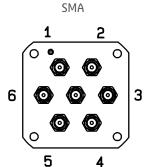


RF CONNECTORS ALLOCATION

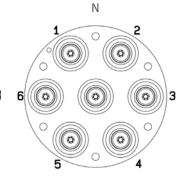
3

SP4T





SP6T





Coaxial Low PIM switches - Electrical schematics

Тур	e	Failsafe	Latching						
		Without option	Without option	Cut-off	C+ and suppression diodes				
		Indicator contact	Indicator contact	Cut-off and I.C.	C+, suppression diodes and I.C.				
0 - 1	Suppression diod		Suppression diodes	Cut-off and TTL Driver	C+ and cut-off				
Optio	ons	Suppression diodes and I.C.	Suppression diodes and I.C.	Cut-off, TTL and I.C.	C+, cut-off and I.C.				
		TTL Driver	TTL Driver	C+					
		TTL Driver and I.C.	TTL Driver and I.C.	C+ and I.C.					
Page SPDT Number DPDT		see page 2-24	see page 2-25	see page 2-26	see page 2-27				
		see page 4-10	see page 4-11	see page 4-12	see page 4-13				

Type		Normally open		Latching		
Options		Without option	C+	Without option	C+	C+ and suppression diodes
		Indicator contact	C+ and I.C.	Indicator contact	C+ and I.C.	C+, suppression diodes and I.C.
		Suppression diodes	C+ and suppression diodes	Suppression diodes		
		Suppression diodes and I.C.	C+, suppression diodes and I.C.	Suppression diodes and I.C.		
Page Number	SPnT	see page 5-32	see page 5-33	see page 5-34	see page 5-35	see page 5-36

